



**ZXTP2027F** 

#### 60V PNP MEDIUM POWER TRANSISTOR IN SOT23

## **Features**

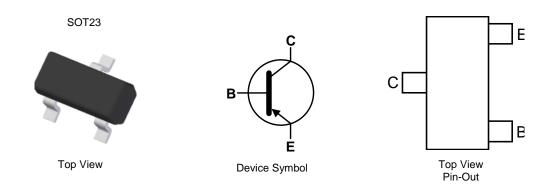
- $BV_{CEO} > -60V$
- I<sub>C</sub> = -4A High Continuous Collector Current
- I<sub>CM</sub> = -10A Peak Pulse Current
- Low Saturation Voltage -60mV Max @  $I_C = -1A$ .
- $R_{CE(SAT)} = 45m\Omega$  at 1A for a Low Equivalent On-Resistance
- 1.2W Power Dissipation
- Complimentary NPN Type: ZXTN2018F
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT23 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight 0.008 grams (Approximate)

## Application

- Gate Driving MOSFETs and IGBTs
- Motor Drive
- Relay, Lamp and Solenoid Drive
- **High Side Switches**



#### Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel	
ZXTP2027FTA 951		7	8	3,000	
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

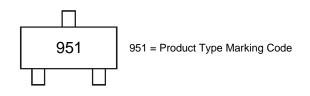
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**





# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-100	V
Collector-Emitter Voltage	V <sub>CEV</sub>	-100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Peak Pulse Collector Current	I <sub>CM</sub>	-10	А
Continuous Collector Current	I <sub>C</sub>	-4	А
Base Current	IB	-1	А

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.0	W
Power Dissipation (Note 6)	PD	1.2	W
Power Dissipation (Note 7)	PD	1.56	W
Thermal Resistance, Junction to Ambient Air (Note 5)	R <sub>0JA</sub>	125	°C/W
Thermal Resistance, Junction to Ambient Air (Note 6)	R <sub>0JA</sub>	104	°C/W
Thermal Resistance, Junction to Ambient Air (Note 7)	R <sub>θJA</sub>	80	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

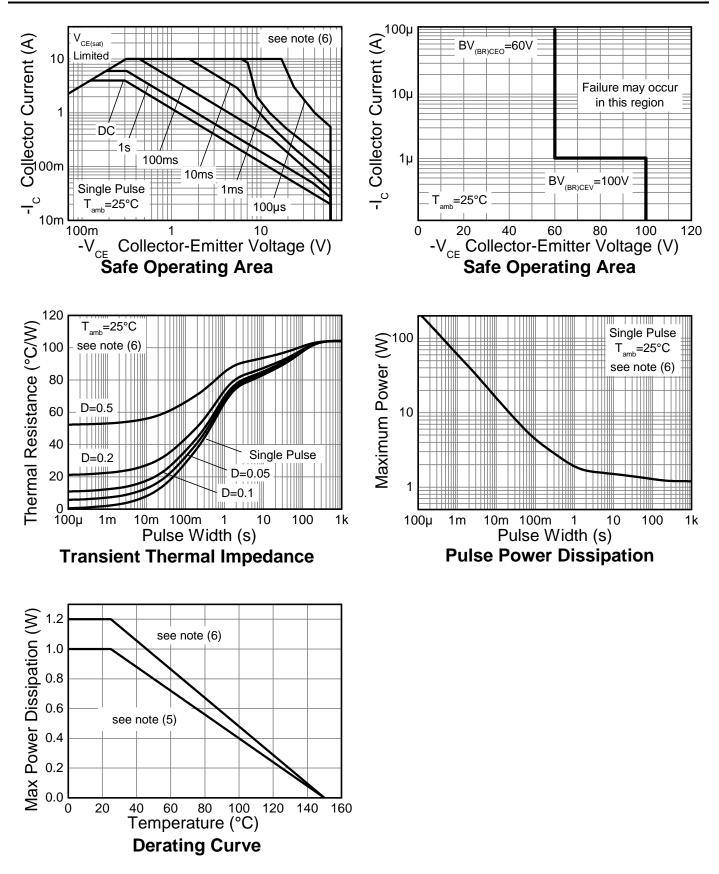
# ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 18mm x 18mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
Same as note (5), except the device is mounted on 30mm x 30mm 2oz copper.
Same as note (6), except measured at t<5secs.</li>
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





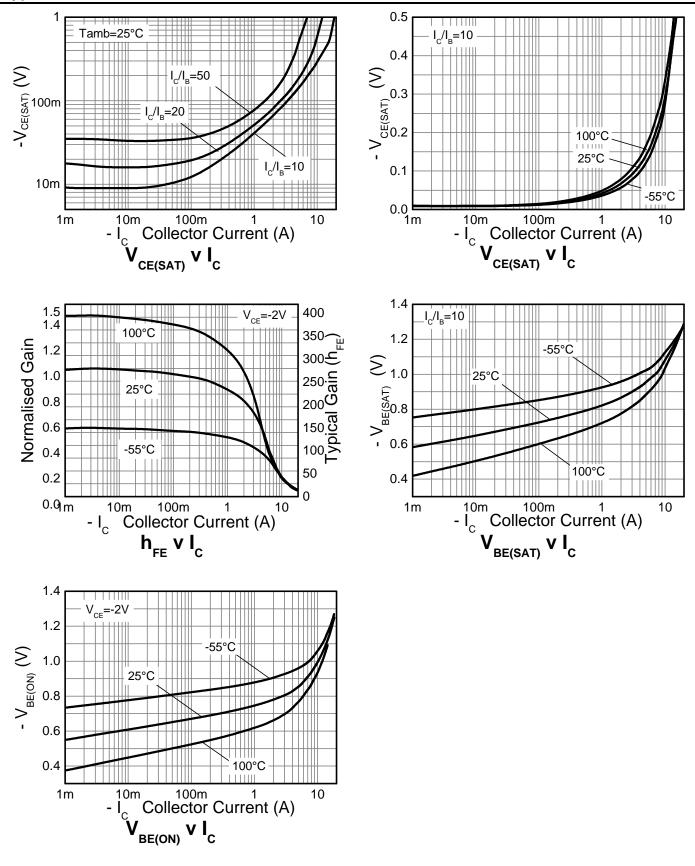
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-100	-120	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage	BV <sub>CEV</sub>	-100	-120	_	V	$I_{C} = -1\mu A$ , $1V > V_{BE} > -0.3V$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-60	-75		V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7.0	-8.2	_	V	I <sub>E</sub> = -100μA
Collector-Emitter Cutoff Current	I <sub>CEV</sub>			-20	nA	$V_{CE} = -80V, V_{BE} = 1V$
Collector-Base Cutoff Current	I <sub>CBO</sub>			-20	nA	$V_{CB} = -80V, I_E = 0$
Emitter-Base Cutoff Current	I <sub>EBO</sub>			-10	nA	$V_{EB} = -6V, I_{C} = 0$
ON CHARACTERISTICS (Note 9)						
		100	250			$V_{CE} = -2V, I_{C} = -10mA$
DC Current Gain	h	100	200	300		$V_{CE} = -2V, I_{C} = -2A$
	h <sub>FE</sub>	80	145	_		$V_{CE} = -2V, I_{C} = -4A$
		20	40			$V_{CE} = -2V, I_{C} = -10A$
			-15	-25	mV	$I_{C} = -100 \text{mA}, I_{B} = -10 \text{mA}$
Collector-Emitter Saturation Voltage	Manua (		-45	-60		$I_{C} = -1A, I_{B} = -100mA$
	V <sub>CE(SAT)</sub>		-70	-95		$I_{C} = -2A, I_{B} = -200mA$
			-155	-240		I <sub>C</sub> = -4A, I <sub>B</sub> = -200mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	-0.89	-1.0	V	I <sub>C</sub> = -4A, I <sub>B</sub> = -200mA
Base-Emitter Turn-On Voltage	V <sub>BE(ON)</sub>		-0.81	-0.95	V	$V_{CE} = -2V, I_{C} = -4A$
SMALL SIGNAL CHARACTERISTICS						
	t <sub>D</sub>		12.6			
Switching times	t <sub>R</sub>		10.2		ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -2A, -I <sub>B1</sub> = I <sub>B2</sub> = -200mA
Switching times	ts		220	_		
	t <sub>F</sub>		21	_		
Transition Frequency	f <sub>T</sub>		165	_	MHz	$V_{CE} = -10V, I_C = -100mA, f = 50MHz$
Output Capacitance	C <sub>OBO</sub>		44		pF	V <sub>CB</sub> = -10V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



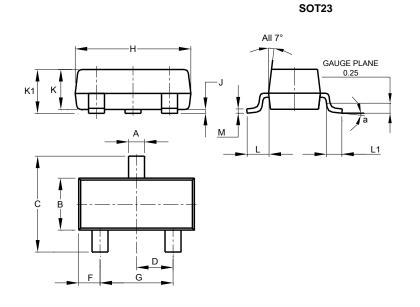
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

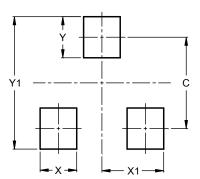
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
ĸ	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



 Dimensions
 Value (in mm)

 C
 2.0

 X
 0.8

 X1
 1.35

 Y
 0.9

 Y1
 2.9

SOT23



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